100 mA Positive Voltage Regulators

The MC78L00A Series of positive voltage regulators are inexpensive, easy-to-use devices suitable for a multitude of applications that require a regulated supply of up to 100 mA. Like their higher powered MC7800 and MC78M00 Series cousins, these regulators feature internal current limiting and thermal shutdown making them remarkably rugged. No external components are required with the MC78L00 devices in many applications.

These devices offer a substantial performance advantage over the traditional zener diode—resistor combination, as output impedance and quiescent current are substantially reduced.

Features

- Wide Range of Available, Fixed Output Voltages
- Low Cost
- Internal Short Circuit Current Limiting
- Internal Thermal Overload Protection
- No External Components Required
- Complementary Negative Regulators Offered (MC79L00A Series)
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

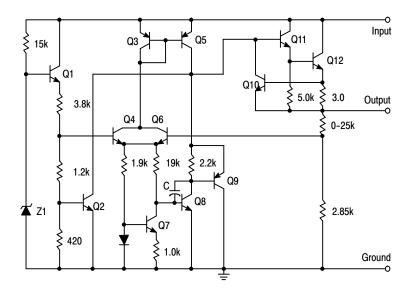
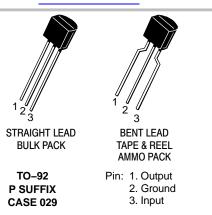


Figure 1. Representative Schematic Diagram



ON Semiconductor®

www.onsemi.com





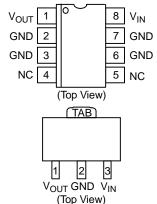
SOIC-8* D SUFFIX CASE 751



SOT-89 CASE 528AG

*SOIC-8 is an internally modified SO-8 package. Pins 2, 3, 6, and 7 are electrically common to the die attach flag. This internal lead frame modification decreases package thermal resistance and increases power dissipation capability when appropriately mounted on a printed circuit board. SOIC-8 conforms to all external dimensions of the standard SO-8 package.

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

DEVICE MARKING INFORMATION

See general marking information in the device marking section on page 12 of this data sheet.

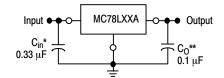


Figure 2. Standard Application

A common ground is required between the input and the output voltages. The input voltage must remain typically 2.0 V above the output voltage even during the low point on the input ripple voltage.

- * C_{in} is required if regulator is located an appreciable distance from power supply filter.
- ** C_0 is not needed for stability; however, it does improve transient response.

ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage (5.0 V–9.0 V) (12 V–18 V) (24 V)	V _I	30 35 40	Vdc
Storage Temperature Range	T _{stg}	-65 to +150	°C
Maximum Junction Temperature	TJ	150	°C
Moisture Sensitivity Level	MSL	1	_
ESD Capability, Human Body Model (Note 1)	ESD _{HBM}	2000	V
ESD Capability, Machine Model (Note 1)	ESD _{MM}	200	V
ESD Capability, Charged Device Model (Note 1)	ESD _{CDM}	2000	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. This device series incorporates ESD protection and is tested by the following methods:
 - ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)
 - ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)
 - ESD Charged Device Model tested per EIA/JES D22/C101, Field Induced Charge Model.

THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Package Dissipation	PD	Internally Limited	W
Thermal Characteristics, TO–92 Thermal Resistance, Junction–to–Ambient	$R_{ heta JA}$	200	°C/W
Thermal Characteristics, SOIC8 Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	Refer to Figure 8	°C/W
Thermal Characteristics, SOT–89 Thermal Resistance, Junction–to–Ambient	$R_{ heta JA}$	55	°C/W

^{2.} Thermal Resistance, Junction-to-Ambient depends on P.C.B. Copper area. See details in Figure 8.

Thermal Resistance, Junction-to-Case is not defined. SOIC 8 lead and TO-92 packages that do not have a heat sink like other packages may have. This is the reason that a Theta JC is never specified. A little heat transfer will occur through the package but since it is plastic, it is minimal. The majority of the heat that is transferred is through the leads where they connect to the circuit board.

ELECTRICAL CHARACTERISTICS (V_I = 10 V, I_O = 40 mA, C_I = 0.33 μ F, C_O = 0.1 μ F, -40° C < T_J < +125 $^{\circ}$ C (for MC78LXXAB, NCV78L05A), 0 $^{\circ}$ C < T_J < +125 $^{\circ}$ C (for MC78LXXAC), unless otherwise noted.)

		MC78L05AC, AB, NCV78L05A			
Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage ($T_J = +25^{\circ}C$)	Vo	4.8	5.0	5.2	Vdc
Line Regulation $(T_J = +25^{\circ}C, I_O = 40 \text{ mA})$ $7.0 \text{ Vdc} \le V_I \le 20 \text{ Vdc}$ $8.0 \text{ Vdc} \le V_I \le 20 \text{ Vdc}$	Reg _{line}	_ _	55 45	150 100	mV
Load Regulation $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 100 \text{ mA})$ $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 40 \text{ mA})$	Reg _{load}	- -	11 5.0	60 30	mV
Output Voltage $ (7.0 \text{ Vdc} \leq \text{V}_{\text{I}} \leq 20 \text{ Vdc}, \ 1.0 \text{ mA} \leq \text{I}_{\text{O}} \leq 40 \text{ mA}) \\ (\text{V}_{\text{I}} = 10 \text{ V}, \ 1.0 \text{ mA} \leq \text{I}_{\text{O}} \leq 70 \text{ mA}) $	Vo	4.75 4.75	<u>-</u> -	5.25 5.25	Vdc
Input Bias Current $(T_J = +25^{\circ}C)$ $(T_J = +125^{\circ}C)$	I _{IB}	_ _	3.8	6.0 5.5	mA
Input Bias Current Change (8.0 Vdc \leq V _I \leq 20 Vdc) (1.0 mA \leq I _O \leq 40 mA)	Δl _{IB}	- -	- -	1.5 0.1	mA
Output Noise Voltage $(T_A = +25^{\circ}C, 10 \text{ Hz} \le f \le 100 \text{ kHz})$	V _n	-	40	-	μV
Ripple Rejection ($I_O = 40 \text{ mA}$, f = 120 Hz, 8.0 Vdc \leq V _I \leq 18 V, T _J = +25°C)	RR	41	49	-	dB
Dropout Voltage (T _J = +25°C)	$V_I - V_O$	-	1.7	-	Vdc

NOTE: NCV78L05A: $T_{low} = -40^{\circ}C$, $T_{high} = +125^{\circ}C$. Guaranteed by design. NCV prefix is for automotive and other applications requiring site and change control.

ELECTRICAL CHARACTERISTICS (V_I = 14 V, I_O = 40 mA, C_I = 0.33 μ F, C_O = 0.1 μ F, -40° C < T_J < +125 $^{\circ}$ C (for MC78LXXAB), 0 $^{\circ}$ C < T_J < +125 $^{\circ}$ C (for MC78LXXAC), unless otherwise noted.)

		MC78L08AC, AB			
Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	7.7	8.0	8.3	Vdc
Line Regulation $(T_J = +25^{\circ}C, I_O = 40 \text{ mA})$ $10.5 \text{ Vdc} \le V_I \le 23 \text{ Vdc}$ $11 \text{ Vdc} \le V_I \le 23 \text{ Vdc}$	Reg _{line}	_ _	20 12	175 125	mV
Load Regulation $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 100 \text{ mA})$ $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 40 \text{ mA})$	Reg _{load}	- -	15 8.0	80 40	mV
Output Voltage $(10.5 \text{ Vdc} \le \text{V}_{\text{I}} \le 23 \text{ Vdc}, 1.0 \text{ mA} \le \text{I}_{\text{O}} \le 40 \text{ mA})$ $(\text{V}_{\text{I}} = 14 \text{ V}, 1.0 \text{ mA} \le \text{I}_{\text{O}} \le 70 \text{ mA})$	Vo	7.6 7.6	_ _	8.4 8.4	Vdc
Input Bias Current $(T_J = +25^{\circ}C)$ $(T_J = +125^{\circ}C)$	I _{IB}	- -	3.0	6.0 5.5	mA
Input Bias Current Change (11 Vdc \leq V _I \leq 23 Vdc) (1.0 mA \leq I _O \leq 40 mA)	$\Delta l_{ m lB}$	- -	-	1.5 0.1	mA
Output Noise Voltage $(T_A = +25^{\circ}C, 10 \text{ Hz} \le f \le 100 \text{ kHz})$	V _n	_	60	_	μV
Ripple Rejection ($I_O = 40 \text{ mA}$, f = 120 Hz, 12 V \leq V _I \leq 23 V, T _J = +25°C)	RR	37	57	-	dB
Dropout Voltage (T _J = +25°C)	$V_I - V_O$	-	1.7	_	Vdc

ELECTRICAL CHARACTERISTICS (V_I = 15 V, I_O = 40 mA, C_I = 0.33 μ F, C_O = 0.1 μ F, -40° C < T_J < +125 $^{\circ}$ C (for MC78LXXAB), 0 $^{\circ}$ C < T_J < +125 $^{\circ}$ C (for MC78LXXAC), unless otherwise noted.)

		М	C78L09AC,	АВ	
Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	8.6	9.0	9.4	Vdc
Line Regulation $ (T_J = +25^{\circ}C, I_O = 40 \text{ mA}) $ $ 11.5 \text{ Vdc} \le V_I \le 24 \text{ Vdc} $ $ 12 \text{ Vdc} \le V_I \le 24 \text{ Vdc} $	Reg _{line}	_ _	20 12	175 125	mV
Load Regulation $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 100 \text{ mA})$ $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 40 \text{ mA})$	Reg _{load}	- -	15 8.0	90 40	mV
Output Voltage (11.5 Vdc \leq V $_{I}$ \leq 24 Vdc, 1.0 mA \leq I $_{O}$ \leq 40 mA) (V $_{I}$ = 15 V, 1.0 mA \leq I $_{O}$ \leq 70 mA)	Vo	8.5 8.5	- -	9.5 9.5	Vdc
Input Bias Current $(T_J = +25^{\circ}C)$ $(T_J = +125^{\circ}C)$	I _{IB}	- -	3.0	6.0 5.5	mA
Input Bias Current Change (11 Vdc \leq V _I \leq 23 Vdc) (1.0 mA \leq I _O \leq 40 mA)	$\Delta I_{ m IB}$	- -	- -	1.5 0.1	mA
Output Noise Voltage $(T_A = +25^{\circ}C, 10 \text{ Hz} \le f \le 100 \text{ kHz})$	V _n	-	60	-	μV
Ripple Rejection ($I_O = 40$ mA, f = 120 Hz, 13 V \leq V _I \leq 24 V, T _J = +25°C)	RR	37	57	-	dB
Dropout Voltage (T _J = +25°C)	V _I – V _O	-	1.7	_	Vdc

ELECTRICAL CHARACTERISTICS (V_I = 19 V, I_O = 40 mA, C_I = 0.33 μ F, C_O = 0.1 μ F, -40° C < T_J < +125°C (for MC78LXXAB), 0°C < T_J < +125°C (for MC78LXXAC), unless otherwise noted.)

		M			
Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	11.5	12	12.5	Vdc
Line Regulation $ (T_J = +25^\circ C, \ I_O = 40 \ Ma) $ $ 14.5 \ Vdc \le V_I \le 27 \ Vdc $ $ 16 \ Vdc \le V_I \le 27 \ Vdc $	Reg _{line}	_ _	120 100	250 200	mV
Load Regulation $ (T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 100 \text{ mA}) \\ (T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 40 \text{ mA}) $	Reg _{load}	_ _	20 10	100 50	mV
Output Voltage $(14.5 \text{ Vdc} \le \text{V}_{\text{I}} \le 27 \text{ Vdc}, 1.0 \text{ mA} \le \text{I}_{\text{O}} \le 40 \text{ mA})$ $(\text{V}_{\text{I}} = 19 \text{ V}, 1.0 \text{ mA} \le \text{I}_{\text{O}} \le 70 \text{ mA})$	Vo	11.4 11.4	- -	12.6 12.6	Vdc
Input Bias Current $(T_J = +25^{\circ}C)$ $(T_J = +125^{\circ}C)$	I _{IB}	- -	4.2 _	6.5 6.0	mA
Input Bias Current Change (16 Vdc \leq V $_{1}$ \leq 27 Vdc) (1.0 mA \leq I $_{O}$ \leq 40 mA)	$\Delta I_{ m IB}$	_ _	_ _	1.5 0.1	mA
Output Noise Voltage $(T_A = +25^{\circ}C, 10 \text{ Hz} \le f \le 100 \text{ kHz})$	V _n	_	80	-	μV
Ripple Rejection (I _O = 40 mA, f = 120 Hz, 15 V \leq V _I \leq 25 V, T _J = +25°C)	RR	37	42	-	dB
Dropout Voltage $(T_J = +25^{\circ}C)$	V _I – V _O	-	1.7	-	Vdc

ELECTRICAL CHARACTERISTICS (V_I = 23 V, I_O = 40 mA, C_I = 0.33 μ F, C_O = 0.1 μ F, -40° C < T_J < +125 $^{\circ}$ C (for MC78LXXAB), 0 $^{\circ}$ C < T_J < +125 $^{\circ}$ C (for MC78LXXAC), unless otherwise noted.)

		MC78L15	AC, AB / NO	CV78L15A	
Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	14.4	15	15.6	Vdc
Line Regulation $ \begin{array}{l} \text{(T}_J = +25^{\circ}\text{C, I}_O = 40 \text{ mA)} \\ 17.5 \text{ Vdc} \leq V_I \leq 30 \text{ Vdc} \\ 20 \text{ Vdc} \leq V_I \leq 30 \text{ Vdc} \end{array} $	Reg _{line}	_ _	130 110	300 250	mV
Load Regulation $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 100 \text{ mA})$ $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 40 \text{ mA})$	Reg _{load}	_ _	25 12	150 75	mV
Output Voltage $(17.5 \text{ Vdc} \le \text{V}_{\text{I}} \le 30 \text{ Vdc}, 1.0 \text{ mA} \le \text{I}_{\text{O}} \le 40 \text{ mA})$ $(\text{V}_{\text{I}} = 23 \text{ V}, 1.0 \text{ mA} \le \text{I}_{\text{O}} \le 70 \text{ mA})$	Vo	14.25 14.25	- -	15.75 15.75	Vdc
Input Bias Current $(T_J = +25^{\circ}C)$ $(T_J = +125^{\circ}C)$	I _{IB}		4.4 _	6.5 6.0	mA
Input Bias Current Change (20 Vdc \leq V $_{I}$ \leq 30 Vdc) (1.0 mA \leq I $_{O}$ \leq 40 mA)	Δl_{IB}	_ _	- -	1.5 0.1	mA
Output Noise Voltage $(T_A = +25^{\circ}C, 10 \text{ Hz} \le f \le 100 \text{ kHz})$	V _n	_	90	-	μV
Ripple Rejection (I _O = 40 mA, f = 120 Hz, 18.5 V \leq V _I \leq 28.5 V, T _J = +25°C)	RR	34	39	_	dB
Dropout Voltage (T _J = +25°C)	$V_I - V_O$	_	1.7	_	Vdc

$\textbf{ELECTRICAL CHARACTERISTICS} \ (V_I = 27 \ V, \ I_O = 40 \ \text{mA}, \ C_I = 0.33 \ \mu\text{F}, \ C_O = 0.1 \ \mu\text{F}, \ 0^{\circ}\text{C} < \text{T}_J < +125^{\circ}\text{C}, \ unless \ otherwise \ noted.)$

Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	17.3	18	18.7	Vdc
Line Regulation $(T_J = +25^{\circ}C, I_O = 40 \text{ mA})$ $21.4 \text{ Vdc} \le V_I \le 33 \text{ Vdc}$ $20.7 \text{ Vdc} \le V_I \le 33 \text{ Vdc}$	Reg _{line}		45	325	mV
22 $\forall dc \le V_1 \le 33 \ \forall dc$ 22 $\forall dc \le V_1 \le 33 \ \forall dc$ 21 $\forall dc \le V_1 \le 33 \ \forall dc$		_	35	275	
Load Regulation $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 100 \text{ mA})$ $(T_J = +25^{\circ}C, 1.0 \text{ mA} \le I_O \le 40 \text{ mA})$	Reg _{load}	- -	30 15	170 85	mV
Output Voltage (21.4 $Vdc \le V_l \le 33 \ Vdc, \ 1.0 \ mA \le I_O \le 40 \ mA)$ (20.7 $Vdc \le V_l \le 33 \ Vdc, \ 1.0 \ mA \le I_O \le 40 \ mA)$ ($V_l = 27 \ V, \ 1.0 \ mA \le I_O \le 70 \ mA)$ ($V_l = 27 \ V, \ 1.0 \ mA \le I_O \le 70 \ mA)$	Vo	17.1 17.1	-	18.9 18.9	Vdc
Input Bias Current $(T_J = +25^{\circ}C)$ $(T_J = +125^{\circ}C)$	I _{IB}	- -	3.1	6.5 6.0	mA
Input Bias Current Change (22 Vdc \leq V $_{I}$ \leq 33 Vdc) (21 Vdc \leq V $_{I}$ \leq 33 Vdc) (1.0 mA \leq I $_{O}$ \leq 40 mA)	Δl _{IB}	_ _	_ _	1.5 0.1	mA
Output Noise Voltage $(T_A = +25^{\circ}C, 10 \text{ Hz} \le f \le 100 \text{ kHz})$	V _n	_	150	-	μV
Ripple Rejection (I _O = 40 mA, f = 120 Hz, 23 V \leq V _I \leq 33 V, T _J = +25°C)	RR	33	48	-	dB
Dropout Voltage $(T_J = +25^{\circ}C)$	V _I – V _O	_	1.7	-	Vdc

ELECTRICAL CHARACTERISTICS (V_I = 33 V, I_O = 40 mA, C_I = 0.33 μ F, C_O = 0.1 μ F, 0°C < T_J < +125°C, unless otherwise noted.)

		MC78L24AC			
Characteristics	Symbol	Min	Тур	Max	Unit
Output Voltage (T _J = +25°C)	Vo	23	24	25	Vdc
Line Regulation $(T_J = +25^{\circ}C, I_O = 40 \text{ mA})$ $27.5 \text{ Vdc} \le V_I \le 38 \text{ Vdc}$ $28 \text{ Vdc} \le V_I \le 80 \text{ Vdc}$ $27 \text{ Vdc} \le V_I \le 38 \text{ Vdc}$	Reg _{line}	- - -	- 50 60	- 300 350	mV
Load Regulation $ \begin{array}{l} (T_J=+25^\circ C, 1.0 \text{ mA} \leq I_O \leq 100 \text{ mA}) \\ (T_J=+25^\circ C, 1.0 \text{ mA} \leq I_O \leq 40 \text{ mA}) \end{array} $	Reg _{load}		40 20	200 100	mV
Output Voltage (28 Vdc \leq V $_{I}$ \leq 38 Vdc, 1.0 mA \leq I $_{O}$ \leq 40 mA) (27 Vdc \leq V $_{I}$ \leq 38 Vdc, 1.0 mA \leq I $_{O}$ \leq 40 mA) (28 Vdc \leq V $_{I}$ \equiv 33 Vdc, 1.0 mA \leq I $_{O}$ \leq 70 mA) (27 Vdc \leq V $_{I}$ \leq 33 Vdc, 1.0 mA \leq I $_{O}$ \leq 70 mA)	Vo	22.8 22.8	-	25.2 25.2	Vdc
Input Bias Current $(T_J = +25^{\circ}C)$ $(T_J = +125^{\circ}C)$	I _{IB}	- -	3.1	6.5 6.0	mA
Input Bias Current Change (28 Vdc \leq V $_{I}$ \leq 38 Vdc) (1.0 mA \leq I $_{O}$ \leq 40 mA)	$\Delta l_{ m IB}$	- -	- -	1.5 0.1	mA
Output Noise Voltage $(T_A = +25^{\circ}C, 10 \text{ Hz} \le f \le 100 \text{ kHz})$	V _n	-	200	-	μV
Ripple Rejection (I _O = 40 mA, f = 120 Hz, 29 V \leq V _I \leq 35 V, T _J = +25°C)	RR	31	45	-	dB
Dropout Voltage $(T_J = +25^{\circ}C)$	V _I – V _O	_	1.7	-	Vdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

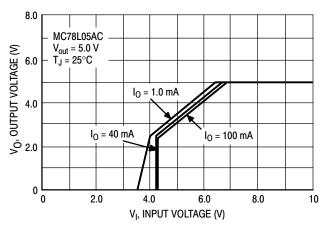


Figure 3. Dropout Characteristics

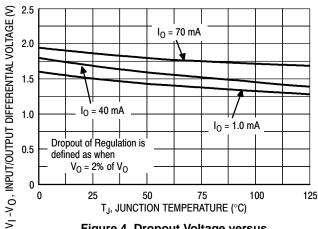


Figure 4. Dropout Voltage versus Junction Temperature

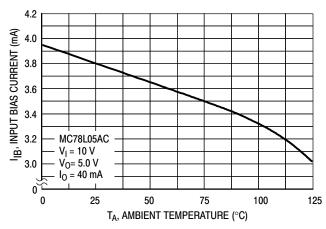


Figure 5. Input Bias Current versus Ambient Temperature

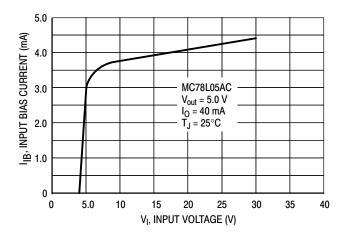


Figure 6. Input Bias Current versus Input Voltage

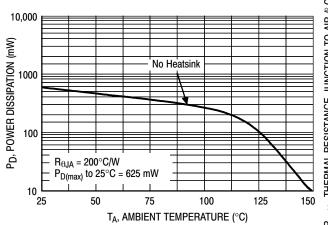


Figure 7. Maximum Average Power Dissipation versus Ambient Temperature – TO-92 Type Package

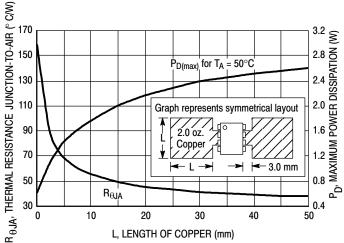


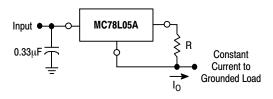
Figure 8. SOIC-8 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

APPLICATIONS INFORMATION

Design Considerations

The MC78L00A Series of fixed voltage regulators are designed with Thermal Overload Protection that shuts down the circuit when subjected to an excessive power overload condition. Internal Short Circuit Protection limits the maximum current the circuit will pass.

In many low current applications, compensation capacitors are not required. However, it is recommended that the regulator input be bypassed with a capacitor if the regulator is connected to the power supply filter with long wire lengths, or if the output load capacitance is large. The



The MC78L00 regulators can also be used as a current source when connected as above. In order to minimize dissipation the MC78L05C is chosen in this application. Resistor R determines the current as follows:

$$I_0 = \frac{5.0 \text{ V}}{\text{B}} + I_{\text{B}}$$

I_{IB} = 3.8 mA over line and load changes

For example, a 100 mA current source would require R to be a 50 Ω , 1/2 W resistor and the output voltage compliance would be the input voltage less 7 V.

Figure 9. Current Regulator

input bypass capacitor should be selected to provide good high–frequency characteristics to insure stable operation under all load conditions. A 0.33 μF or larger tantalum, mylar, or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with the shortest possible leads directly across the regulators input terminals. Good construction techniques should be used to minimize ground loops and lead resistance drops since the regulator has no external sense lead. Bypassing the output is also recommended.

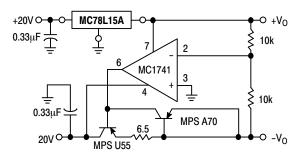


Figure 10. ±15 V Tracking Voltage Regulator

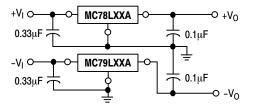


Figure 11. Positive and Negative Regulator

ORDERING INFORMATION

Device	Output Voltage	Operating Temperature Range	Package	Shipping [†]
MC78L05ABDG	5.0 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
NCV78L05ABDG*	5.0 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
MC78L05ABDR2G	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCV78L05ABDR2G*	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L05ABPG	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
NCV78L05ABPG*	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L05ABPRAG	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
NCV78L05ABPRAG*	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L05ABPREG	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
NCV78L05ABPREG*	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L05ABPRMG	5.0 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
NCV78L05ABPRMG*	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
NCV78L05ABPRPG*	5.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L05ACDG	5.0 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
MC78L05ACDR2G	5.0 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L05ACPG	5.0 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L05ACPRAG	5.0 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L05ACPREG	5.0 V	$T_J = 0^\circ$ to +125°C	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L05ACPRMG	5.0 V	$T_J = 0^\circ$ to +125°C	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L05ACPRPG	5.0 V	$T_J = 0^\circ$ to +125°C	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L05ACHT1G	5.0 V	$T_J = 0^\circ$ to +125°C	SOT-89 (Pb-Free)	2500 / Tape & Reel
MC78L08ABDG	8.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail

^{*}NCV78L05A, NCV78L12A, NCV78L15A: $T_{low} = -40^{\circ}C$, $T_{high} = +125^{\circ}C$. Guaranteed by design. NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ORDERING INFORMATION (continued)

Device	Output Voltage	Operating Temperature Range	Package	Shipping [†]
MC78L08ABDR2G	8.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCV78L08ABDR2G*	8.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L08ABPG	8.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L08ABPRAG	8.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L08ABPRPG	8.0 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L08ACDG	8.0 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
MC78L08ACDR2G	8.0 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L08ACPG	8.0 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L08ACPRAG	8.0 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L08ACPREG	8.0 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L08ACPRPG	8.0 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L09ABDG	9.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
MC78L09ABDR2G	9.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L09ABPRAG	9.0 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L09ABPRPG	9.0 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L09ACDG	9.0 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
MC78L09ACDR2G	9.0 V	$T_J = 0^\circ$ to +125°C	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L09ACPG	9.0 V	$T_J = 0^\circ$ to +125°C	TO-92 (Pb-Free)	2000 Units / Bag
MC78L12ABDG	12 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
MC78L12ABDR2G	12 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCV78L12ABDG*	12 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
NCV78L12ABDR2G*	12 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L12ABPG	12 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag

^{*}NCV78L05A, NCV78L12A, NCV78L15A: T_{low} = -40°C, T_{high} = +125°C. Guaranteed by design. NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable. †For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ORDERING INFORMATION (continued)

Device	Output Voltage	Operating Temperature Range	Package	Shipping [†]
MC78L12ABPRPG	12 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
NCV78L12ABPG*	12 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L12ACDG	12 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
MC78L12ACDR2G	12 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L12ACPG	12 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L12ACPRAG	12 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L12ACPREG	12 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L12ACPRMG	12 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L12ACPRPG	12 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L15ABDG	15 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
MC78L15ABDR2G	15 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
NCV78L15ABDR2G*	15 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L15ABPG	15 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L15ABPRAG	15 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L15ABPRPG	15 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L15ACDG	15 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	98 Units / Rail
MC78L15ACDR2G	15 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC78L15ACPG	15 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L15ACPRAG	15 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L15ACPRPG	15 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L18ABPG	18 V	$T_J = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L18ACPG	18 V	T _J = 0° to +125°C	TO-92 (Pb-Free)	2000 Units / Bag
MC78L18ACPRAG	18 V	T _J = 0° to +125°C	TO-92 (Pb-Free)	2000 / Tape & Reel

^{*}NCV78L05A, NCV78L12A, NCV78L15A: $T_{low} = -40^{\circ}C$, $T_{high} = +125^{\circ}C$. Guaranteed by design. NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

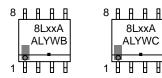
ORDERING INFORMATION (continued)

Device	Output Voltage	Operating Temperature Range	Package	Shipping [†]
MC78L18ACPRMG	18 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L18ACPRPG	18 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack
MC78L24ABPG	24 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
NCV78L24ABPRPG*	24 V	$T_{J} = -40^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L24ACPG	24 V	$T_J = 0^\circ \text{ to } +125^\circ \text{C}$	TO-92 (Pb-Free)	2000 Units / Bag
MC78L24ACPRAG	24 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Tape & Reel
MC78L24ACPRPG	24 V	$T_{J} = 0^{\circ} \text{ to } +125^{\circ}\text{C}$	TO-92 (Pb-Free)	2000 / Ammo Pack

^{*}NCV78L05A, NCV78L12A, NCV78L15A: T_{low} = -40°C, T_{high} = +125°C. Guaranteed by design. NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable. †For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications.

MARKING DIAGRAMS





= 05, 08, 09, 12, or 15 XX

Α = Assembly Location

L = Wafer Lot Υ = Year

W = Work Week

B, C = Temperature Range

= Pb-Free Package

SOT-89 CASE 528AG

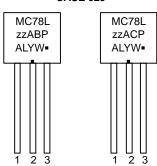


= Year

= Work Week

XX = Specific Device Code

TO-92 **P SUFFIX CASE 029**



= 05, 08, 09, 12, 15, 18 or 24

Α = Assembly Location

= Wafer Lot

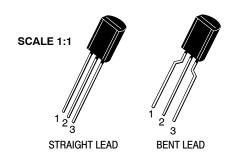
= Year

= Work Week

= Pb-Free Package

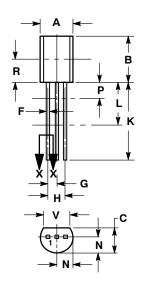
(Note: Microdot may be in either location)

tions Brochure, BRD8011/D.



TO-92 (TO-226) 1 WATT CASE 29-10 **ISSUE A**

DATE 08 MAY 2012



STRAIGHT LEAD







NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- 714.5M, 1994.
 CONTROLLING DIMENSION: INCHES.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS
 UNCONTROLLED.
- UNIONI HOLLEU, DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L DIMENSIONS D AND J APPLY BETWEEN DI-MENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
Р		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ASME
- CONTROLLING DIMENSION: INCHES.
 CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- DIMENSION F APPLIES BETWEEN DIMENSIONS P AND L. DIMENSIONS D AND J APPLY BETWEEN DIMENSIONS L AND K MINIMUM. THE LEAD DIMENSIONS ARE UNCONTROLLED IN DIMENSION P AND BEYOND DIMENSION K MINIMUM.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.44	5.21
В	0.290	0.310	7.37	7.87
С	0.125	0.165	3.18	4.19
D	0.018	0.021	0.46	0.53
G	0.094	0.102	2.40	2.80
J	0.018	0.024	0.46	0.61
K	0.500		12.70	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.135		3.43	
٧	0.135		3.43	

STYLES ON PAGE 2

DOCUMENT NUMBER:	98AON52857E	Electronic versions are uncontrolled except when accessed directly from the Document R Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	TO-92 (TO-226) 1 WATT		PAGE 1 OF 2

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

SEATING PLANE

TO-92 (TO-226) 1 WATT CASE 29-10

ISSUE A

DATE 08 MAY 2012

STYLE 1: PIN 1. 2. 3.	EMITTER BASE COLLECTOR	STYLE 2: PIN 1. 2. 3.	BASE EMITTER COLLECTOR	STYLE 3: PIN 1. 2. 3.	ANODE ANODE CATHODE	STYLE 4: PIN 1. 2. 3.	CATHODE CATHODE ANODE	STYLE 5: PIN 1. 2. 3.	DRAIN SOURCE GATE
STYLE 6: PIN 1. 2. 3.	GATE SOURCE & SUBSTRATE DRAIN	STYLE 7: PIN 1. 2. 3.	SOURCE DRAIN GATE	STYLE 8: PIN 1. 2. 3.	DRAIN GATE SOURCE & SUBSTRATE	STYLE 9: PIN 1. 2. 3.	BASE 1 EMITTER BASE 2	STYLE 10: PIN 1. 2. 3.	
2. 3.	CATHODE & ANODE CATHODE	2. 3.	GATE MAIN TERMINAL 2	2. 3.		2. 3.	COLLECTOR BASE	2. 3.	CATHODE ANODE 2
STYLE 16: PIN 1. 2. 3.	ANODE GATE CATHODE	STYLE 17: PIN 1. 2. 3.	COLLECTOR BASE EMITTER	STYLE 18: PIN 1. 2. 3.	ANODE CATHODE NOT CONNECTED	STYLE 19: PIN 1. 2. 3.	GATE ANODE CATHODE	STYLE 20: PIN 1. 2. 3.	NOT CONNECTED CATHODE ANODE
PIN 1. 2.	COLLECTOR EMITTER	PIN 1.		PIN 1. 2.	GATE SOURCE DRAIN	PIN 1. 2.	EMITTER COLLECTOR/ANODE CATHODE	PIN 1. 2.	MT 1
3.	V _{CC} GROUND 2 OUTPUT	PIN 1. 2. 3.	MT SUBSTRATE MT	PIN 1. 2. 3.	ANODE GATE	PIN 1. 2. 3.	NOT CONNECTED ANODE CATHODE	PIN 1. 2.	DRAIN
2.	GATE DRAIN SOURCE	2.	BASE COLLECTOR EMITTER	2.	RETURN INPUT OUTPUT	2.	INPUT GROUND LOGIC		GATE COLLECTOR EMITTER

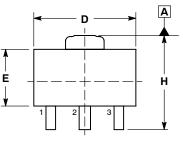
DOCUMENT NUMBER:	98AON52857E	Electronic versions are uncontrolled except when accessed directly from the Document Reposit Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	TO-92 (TO-226) 1 WATT		PAGE 2 OF 2

ON Semiconductor and IN are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

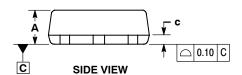


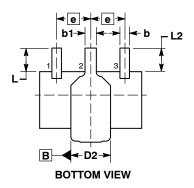
SOT-89, 3 LEAD CASE 528AG **ISSUE O**

DATE 04 MAR 2014



TOP VIEW





- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

- Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
 LEAD THICKNESS INCLUDES LEAD FINISH.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD
 FLASH, PROTRUSIONS, OR GATE BURRS.
 DIMENSIONS L, L2, D2, AND H ARE MEASURED AT
 DATUM PLANE C.
 CENTER LEAD CONTOUR MAY VARY WITHIN THE
 REGION DEFINED BY DIMENSION E.
 DIMENSION D2 IS DEFINED AT ITS WIDEST POINT.

	MILLIMETERS			
DIM	MIN MAX			
Α	1.40	1.60		
b	0.38	0.47		
b1	0.46	0.55		
С	0.40	0.44		
D	4.40	4.60		
D2	1.60	1.90		
E	2.40	2.60		
е	1.50 BSC			
Н	4.05	4.25		
L	0.89	1.20		

GENERIC MARKING DIAGRAM*

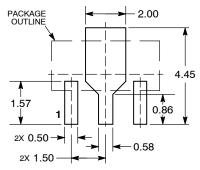


= Year

W = Work Week

= Specific Device Code

RECOMMENDED MOUNTING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

DOCUMENT NUMBER:	98AON82692F	Electronic versions are uncontrolled except when accessed directly from the Document Reprinted versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOT-89, 3 LEAD		PAGE 1 OF 1

ON Semiconductor and unare trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

^{*}This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G", may or not be present.



SOIC-8 NB CASE 751-07 **ISSUE AK**

DATE 16 FEB 2011



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
C	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27	1.27 BSC		0.050 BSC	
Н	0.10	0.25	0.004	0.010	
7	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
М	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

SOLDERING FOOTPRINT*



^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

GENERIC MARKING DIAGRAM*



XXXXX = Specific Device Code = Assembly Location = Wafer Lot

= Year = Work Week

= Pb-Free Package



XXXXXX = Specific Device Code = Assembly Location Α

= Year ww

= Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLES ON PAGE 2

DOCUMENT NUMBER:	98ASB42564B	Electronic versions are uncontrolled except when accessed directly from the Document Repo Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.		
DESCRIPTION:	SOIC-8 NB		PAGE 1 OF 2	

ON Semiconductor and un are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

SOIC-8 NB CASE 751-07 ISSUE AK

DATE 16 FEB 2011

STYLE 2: PIN 1. COLLECTOR, DIE, #1 2. COLLECTOR, #1 3. COLLECTOR, #2 4. COLLECTOR, #2 6. EMITTER, #2 7. BASE, #1 8. EMITTER, #1 STYLE 6: PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE STYLE 10: PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND 5. GROUND 6. PINS 2	STYLE 3: PIN 1. DRAIN, DIE #1 2. DRAIN, #1 3. DRAIN, #2 4. DRAIN, #2 5. GATE, #2 6. SOURCE, #2 7. GATE, #1 8. SOURCE, #1 STYLE 7: PIN 1. IMPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2	3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE 2. SOURCE
PIN 1. SOURCE 2. DRAIN 3. DRAIN 4. SOURCE 5. SOURCE 6. GATE 7. GATE 8. SOURCE STYLE 10: PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND	PIN 1. INPUT 2. EXTERNAL BYPASS 3. THIRD STAGE SOURCE 4. GROUND 5. DRAIN 6. GATE 3 7. SECOND STAGE Vd 8. FIRST STAGE Vd STYLE 11: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2	PIN 1. COLLECTOR, DIE #1 2. BASE, #1 3. BASE, #2 4. COLLECTOR, #2 5. COLLECTOR, #2 6. EMITTER, #2 7. EMITTER, #1 8. COLLECTOR, #1 STYLE 12: PIN 1. SOURCE 2. SOURCE
PIN 1. GROUND 2. BIAS 1 3. OUTPUT 4. GROUND	PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2	PIN 1. SOURCE 2. SOURCE
6. BIAS 2 7. INPUT 8. GROUND	5. DRAIN 2 6. DRAIN 2 7. DRAIN 1 8. DRAIN 1	3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 14: PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN	STYLE 15: PIN 1. ANODE 1 2. ANODE 1 3. ANODE 1 4. ANODE 1 5. CATHODE, COMMON 6. CATHODE, COMMON 7. CATHODE, COMMON 8. CATHODE, COMMON	STYLE 16: PIN 1. EMITTER, DIE #1 2. BASE, DIE #1 3. EMITTER, DIE #2 4. BASE, DIE #2 5. COLLECTOR, DIE #2 6. COLLECTOR, DIE #2 7. COLLECTOR, DIE #1 8. COLLECTOR, DIE #1
STYLE 18: PIN 1. ANODE 2. ANODE 3. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. CATHODE 8. CATHODE	STYLE 19: PIN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 2 5. DRAIN 2 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1	STYLE 20: PIN 1. SOURCE (N) 2. GATE (N) 3. SOURCE (P) 4. GATE (P) 5. DRAIN 6. DRAIN 7. DRAIN 8. DRAIN
STYLE 22: PIN 1. I/O LINE 1 2. COMMON CATHODE/VCC 3. COMMON CATHODE/VCC 4. I/O LINE 3 5. COMMON ANODE/GND 6. I/O LINE 4 7. I/O LINE 5 8. COMMON ANODE/GND	STYLE 23: PIN 1. LINE 1 IN 2. COMMON ANODE/GND 3. COMMON ANODE/GND 4. LINE 2 IN 5. LINE 2 OUT 6. COMMON ANODE/GND 7. COMMON ANODE/GND 8. LINE 1 OUT	STYLE 24: PIN 1. BASE 2. EMITTER 3. COLLECTOR/ANODE 4. COLLECTOR/ANODE 5. CATHODE 6. CATHODE 7. COLLECTOR/ANODE 8. COLLECTOR/ANODE
STYLE 26: PIN 1. GND 2. dv/dt 3. ENABLE 4. ILIMIT 5. SOURCE 6. SOURCE 7. SOURCE 8. VCC	STYLE 27: PIN 1. ILIMIT 2. OVLO 3. UVLO 4. INPUT+ 5. SOURCE 6. SOURCE 7. SOURCE 8. DRAIN	STYLE 28: PIN 1. SW_TO_GND 2. DASIC_OFF 3. DASIC_SW_DET 4. GND 5. V_MON 6. VBULK 7. VBULK 8. VIN
STYLE 30: PIN 1. DRAIN 1 2. DRAIN 1 3. GATE 2 4. SOURCE 2 5. SOURCE 1/DRAIN 2 6. SOURCE 1/DRAIN 2 7. SOURCE 1/DRAIN 2 8. GATE 1		
	PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. SOURCE 4. GATE 5. DRAIN 6. DRAIN 7. CATHODE 8. CATHODE 8. CATHODE 8. CATHODE 8. CATHODE 9. COMMON CATHODE/VCC 9. COMMON CATHODE/VCC 1. (/O LINE 1 2. COMMON CATHODE/VCC 1. (/O LINE 3 5. COMMON ANODE/GND 6. (/O LINE 5 8. COMMON ANODE/GND 8.	PIN 1. N-SOURCE 2. N-GATE 3. P-SOURCE 4. P-GATE 5. P-DRAIN 6. P-DRAIN 7. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. N-DRAIN 8. N-DRAIN 7. CATHODE, COMMON 8. N-DRAIN 8. CATHODE, COMMON 8. CATHODE 9IN 1. SOURCE 1 2. GATE 1 3. SOURCE 2 4. GATE 4. GATE 2 5. DRAIN 6. MIRROR 2 7. DRAIN 1 8. MIRROR 1 8. COMMON CATHODE/VCC 1. COMMON CATHODE/VCC 1. COMMON CATHODE/VCC 1. (/O LINE 1 2. COMMON CATHODE/VCC 1. (/O LINE 3 5. COMMON ANODE/GND 6. (/O LINE 4 7. (/O LINE 5 8. COMMON ANODE/GND 8. LINE 2 OUT 9. COMMON ANODE/GND 8. LINE 1 OUT STYLE 26: PIN 1. GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 27: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 28: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. LINE 1 OUT STYLE 29: PIN 1. ILIMIT 9. COMMON ANODE/GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. COMMON ANODE/GND 9. LINE 2 OUT 9. COMMON ANODE/GND 9. COMM

DOCUMENT NUMBER:	98ASB42564B	Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.			
DESCRIPTION:	SOIC-8 NB		PAGE 2 OF 2		

ON Semiconductor and IN are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

ON Semiconductor and the are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor and see no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor products for any such unintended or unauthorized application, Buyer shall indemnify and

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:
Email Requests to: orderlit@onsemi.com

ON Semiconductor Website: www.onsemi.com

TECHNICAL SUPPORT North American Technical Support: Voice Mail: 1 800-282-9855 Toll Free USA/Canada Phone: 011 421 33 790 2910

Europe, Middle East and Africa Technical Support:

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

ON Semiconductor:

MC78L15ACPXA NCV78L05ABDR2G NCV78L12ABDR2 NCV78L12ABDR2G MC78L05ABDG MC78L05ABDR2G MC78L05ABPRAG MC78L05ABPRAG MC78L05ABPRAG MC78L05ABPRAG MC78L05ABPRAG MC78L05ACPRAG MC78L05ACPRAG MC78L05ACPRAG MC78L05ACPRAG MC78L05ACPRAG MC78L05ACPRAG MC78L05ACPRAG MC78L08ABPRAG MC78L08ABPRAG MC78L08ABPRAG MC78L08ACPRAG MC78L09ACPRAG MC78L09ACPRAG MC78L09ACPRAG MC78L09ACPRAG MC78L09ACPRAG MC78L09ACPRAG MC78L09ACPRAG MC78L09ACPRAG MC78L12ABPRAG MC78L12ABPRAG MC78L12ABPRAG MC78L12ACPRAG MC78L12ACPRAG MC78L12ACPRAG MC78L12ACPRAG MC78L12ACPRAG MC78L15ABPRAG MC78L15ABPRAG MC78L15ABPRAG MC78L15ABPRAG MC78L15ABPRAG MC78L15ACPRAG MC78L05ABPRAG MC78L05ABPRAG NCV78L05ABPRAG NCV